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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Details	
Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	LINbus, SIO, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	25
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1.5K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	A/D 9x10b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f212l4snfp-x6

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

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# RENESAS

R8C/2K Group, R8C/2L Group RENESAS MCU

## 1. Overview

#### 1.1 Features

The R8C/2K Group and R8C/2L Group of single-chip MCUs incorporates the R8C/Tiny Series CPU core, employing sophisticated instructions for a high level of efficiency. With 1 Mbyte of address space, and it is capable of executing instructions at high speed. In addition, the CPU core boasts a multiplier for high-speed operation processing.

Power consumption is low, and the supported operating modes allow additional power control. These MCUs also use an anti-noise configuration to reduce emissions of electromagnetic noise and are designed to withstand EMI. Integration of many peripheral functions, including multifunction timer and serial interface, reduces the number of system components.

Furthermore, the R8C/2L Group has on-chip data flash (1 KB  $\times$  2 blocks).

The difference between the R8C/2K Group and R8C/2L Group is only the presence or absence of data flash. Their peripheral functions are the same.

### 1.1.1 Applications

Electronic household appliances, office equipment, audio equipment, consumer equipment, etc.



## 1.1.2 Specifications

Tables 1.1 and 1.2 outlines the Specifications for R8C/2K Group and Tables 1.3 and 1.4 outlines the Specifications for R8C/2L Group.

Item	Function	Specification	
CPU	Central processing	R8C/Tiny series core	
	unit	Number of fundamental instructions: 89	
		Minimum instruction execution time:	
		50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V)	
		100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)	
		200  ns (f(XIN) = 5  MHz, VCC = 2.2  to  5.5  V)	
		• Multiplier: 16 bits $\times$ 16 bits $\rightarrow$ 32 bits	
		• Multiply-accumulate instruction: 16 bits $\times$ 16 bits $+$ 32 bits $\rightarrow$ 32 bits	
		Operation mode: Single-chip mode (address space: 1 Mbyte)	
Memory	ROM, RAM	Refer to Table 1.5 Product List for R8C/2K Group.	
Power Supply	Voltage detection	Power-on reset	
Voltage	circuit	Voltage detection 3	
Detection	Circuit	· Voltage detection 3	
I/O Ports	Programmable I/O	Input-only: 3 pins	
1/01/01/3	ports	CMOS I/O ports: 25, selectable pull-up resistor	
	pons	<ul> <li>High current drive ports: 8</li> </ul>	
Clock	Clask gaparation		
CIOCK	Clock generation	2 circuits: XIN clock oscillation circuit (with on-chip feedback resistor), On-chip oscillator (high-speed, low-speed)	
	circuits		
		(high-speed on-chip oscillator has a frequency adjustment function)	
		Oscillation stop detection: XIN clock oscillation stop detection function	
		• Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16	
		Low power consumption modes:	
		Standard operating mode (high-speed clock, high-speed on-chip oscillator,	
		low-speed on-chip oscillator), wait mode, stop mode	
Interrupts		<ul> <li>External: 4 sources, Internal: 15 sources, Software: 4 sources</li> </ul>	
		Priority levels: 7 levels	
Watchdog Tim		15 bits $\times$ 1 (with prescaler), reset start selectable	
Timer	Timer RA	8 bits x 1 (with 8-bit prescaler)	
		Timer mode (period timer), pulse output mode (output level inverted every	
		period), event counter mode, pulse width measurement mode, pulse period	
		measurement mode	
	Timer RB	8 bits × 1 (with 8-bit prescaler)	
		Timer mode (period timer), programmable waveform generation mode (PWM	
		output), programmable one-shot generation mode, programmable wait one-	
		shot generation mode	
	Timer RC	16 bits × 1 (with 4 capture/compare registers)	
		Timer mode (input capture function, output compare function), PWM mode	
		(output 3 pins), PWM2 mode (PWM output pin)	
	Timer RD	16 bits × 2 (with 4 capture/compare registers)	
		Timer mode (input capture function, output compare function), PWM mode	
		(output 6 pins), reset synchronous PWM mode (output three-phase	
		waveforms (6 pins), sawtooth wave modulation), complementary PWM mode	
		(output three-phase waveforms (6 pins), triangular wave modulation), PWM3	
		mode (PWM output 2 pins with fixed period)	

 Table 1.1
 Specifications for R8C/2K Group (1)

Table 1.3	Specifications to	r R8C/2L Group (1)
Item	Function	Specification
CPU	Central processing	R8C/Tiny series core
	unit	Number of fundamental instructions: 89
		Minimum instruction execution time:
		50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V)
		100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
		200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V)
		• Multiplier: 16 bits $\times$ 16 bits $\rightarrow$ 32 bits
		• Multiply-accumulate instruction: 16 bits $\times$ 16 bits $+$ 32 bits $\rightarrow$ 32 bits
		Operation mode: Single-chip mode (address space: 1 Mbyte)
Memory	ROM, RAM	Refer to Table 1.6 Product List for R8C/2L Group.
Power Supply	Voltage detection	Power-on reset
Voltage	circuit	Voltage detection 3
Detection	Circuit	· Vollage detection o
I/O Ports	Programmable I/O	Input-only: 3 pins
1/01/01/3	ports	CMOS I/O ports: 25, selectable pull-up resistor
	pons	<ul> <li>High current drive ports: 8</li> </ul>
Clock	Clock generation	2 circuits: XIN clock oscillation circuit (with on-chip feedback resistor),
CIUCK	circuits	
	circuits	On-chip oscillator (high-speed, low-speed)
		(high-speed on-chip oscillator has a frequency adjustment function)
		Oscillation stop detection: XIN clock oscillation stop detection function
		• Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16
		Low power consumption modes:
		Standard operating mode (high-speed clock, high-speed on-chip oscillator,
-		low-speed on-chip oscillator), wait mode, stop mode
Interrupts		• External: 4 sources, Internal: 15 sources, Software: 4 sources
		Priority levels: 7 levels
Watchdog Time		15 bits x 1 (with prescaler), reset start selectable
Timer	Timer RA	8 bits × 1 (with 8-bit prescaler)
		Timer mode (period timer), pulse output mode (output level inverted every
		period), event counter mode, pulse width measurement mode, pulse period
		measurement mode
	Timer RB	8 bits × 1 (with 8-bit prescaler)
		Timer mode (period timer), programmable waveform generation mode (PWM
		output), programmable one-shot generation mode, programmable wait one-
	<b>T D</b> 0	shot generation mode
	Timer RC	16 bits × 1 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode
	Timer RD	(output 3 pins), PWM2 mode (PWM output pin)
	Timer RD	16 bits x 2 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode
		(output 6 pins), reset synchronous PWM mode (output three-phase
		waveforms (6 pins), sawtooth wave modulation), complementary PWM mode
		(output three-phase waveforms (6 pins), triangular wave modulation), PWM3
		mode (PWM output 2 pins with fixed period)

Table 1.3Specifications for R8C/2L Group (1)

Item	Function	Specification
Serial	UART0, UART2	Clock synchronous serial I/O/UART × 2
Interface		
LIN Module		Hardware LIN: 1 (timer RA, UART0)
A/D Converter		10-bit resolution × 9 channels, includes sample and hold function
Flash Memory		<ul> <li>Programming and erasure voltage: VCC = 2.7 to 5.5 V</li> </ul>
		<ul> <li>Programming and erasure endurance: 10,000 times (data flash)</li> </ul>
		1,000 times (program ROM)
		<ul> <li>Program security: ROM code protect, ID code check</li> </ul>
		<ul> <li>Debug functions: On-chip debug, on-board flash rewrite function</li> </ul>
Operating Free	luency/Supply	f(XIN) = 20  MHz (VCC = 3.0  to  5.5  V)
Voltage		f(XIN) = 10 MHz (VCC = 2.7 to 5.5 V) f(XIN) = 5 MHz (VCC = 2.2 to 5.5 V) (VCC = 2.7 to 5.5 V for A/D converter only)
Current consur	nption	Typ. 10 mA (VCC = 5.0 V, f(XIN) = 20 MHz)
		Typ. 6 mA (VCC = 3.0 V, $f(XIN) = 10 \text{ MHz})'$
		Typ. 23 $\mu$ A (VCC = 3.0 V, wait mode, low-speed on-chip oscillator used) Typ. 0.7 $\mu$ A (VCC = 3.0 V, stop mode)
Operating Ambient Temperature		-20 to 85°C (N version)
		-40 to 85°C (D version) <sup>(1)</sup>
		-20 to 105°C (Y version) <sup>(2)</sup>
Package		32-pin LQFP
		Package code: PLQP0032GB-A (previous code: 32P6U-A)

 Table 1.4
 Specifications for R8C/2L Group (2)

1. Specify the D version if D version functions are to be used.

2. Please contact Renesas Technology sales offices for the Y version.



#### **Pin Functions** 1.5

Table 1.8 lists Pin Functions.

#### Table 1.8 **Pin Functions**

Item	Pin Name	I/O Type	Description
Power supply input	VCC, VSS	-	Apply 2.2 V to 5.5 V to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply input	AVCC, AVSS	-	Power supply for the A/D converter. Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between
XIN clock output	XOUT	0	the XIN and XOUT pins <sup>(1)</sup> . To use an external clock, input it to the XIN pin and leave the XOUT pin open.
INT interrupt input	INTO, INT1, INT3	I	INT interrupt input pins. INT0 is timer RB, timer RC and timer RD input pins.
Key input interrupt	KI0 to KI3	I	Key input interrupt input pins
Timer RA	TRAIO	I/O	Timer RA I/O pin
Timer RB	TRBO	0	Timer RB output pin
Timer RC	TRCCLK	I	External clock input pin
	TRCTRG	I	External trigger input pin
	TRCIOA, TRCIOB, TRCIOC, TRCIOD	I/O	Timer RC I/O pins
Timer RD	TRDIOA0, TRDIOA1, TRDIOB0, TRDIOB1, TRDIOC0, TRDIOC1, TRDIOD0, TRDIOD1	RDIOA0, TRDIOA1,       I/O       Timer RD I/O pins         'RDIOB0, TRDIOB1,       'RDIOC0, TRDIOC1,       I/O	
	TRDCLK	Ι	External clock input pin
Serial interface	CLK0, CLK2	I/O	Transfer clock I/O pins
	RXD0, RXD2	I	Serial data input pins
	TXD0, TXD2	0	Serial data output pins
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN2, AN4 to AN11	I	Analog input pins to A/D converter
I/O port	P0_0 to P0_3, P0_5, P1_0 to P1_7, P2_0 to P2_7, P3_3 to P3_5, P4_5,	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P2_0 to P2_7 also function as LED drive ports.
Input port	P4_2, P4_6, P4_7	I	Input-only ports

I: Input O: Output

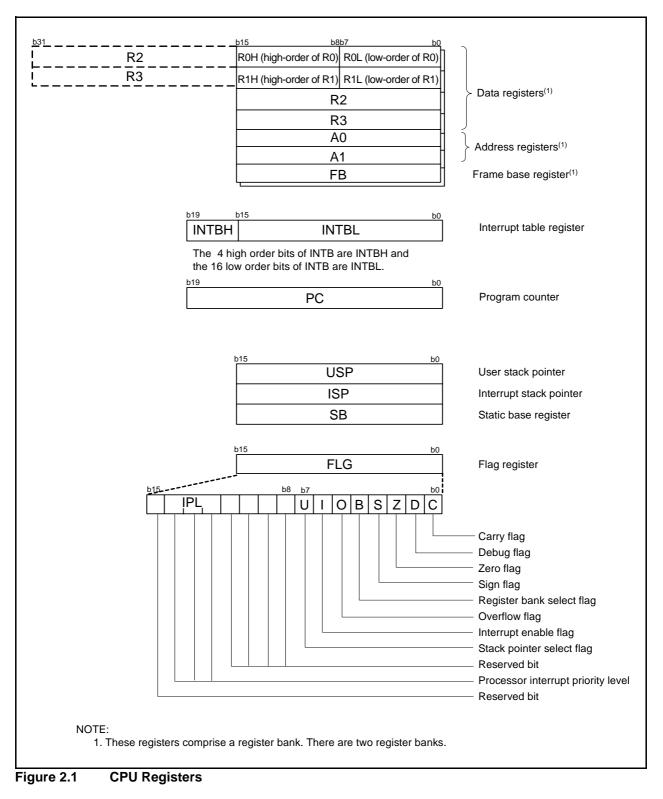
NOTE:

I/O: Input and output

1. Refer to the oscillator manufacturer for oscillation characteristics.

## 2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.



## 2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

## 2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 and as a 32-bit address register (A1A0).

### 2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

#### 2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register that indicates the start address of an interrupt vector table.

## 2.5 Program Counter (PC)

PC is 20 bits wide and indicates the address of the next instruction to be executed.

## 2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP, and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

### 2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

#### 2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

## 2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

## 2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

## 2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

## 2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

## 2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

#### 2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.

#### 2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.

Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

## 2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1. The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

### 2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7. If a requested interrupt has higher priority than IPL, the interrupt is enabled.

#### 2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

#### **Special Function Registers (SFRs)** 4.

An SFR (special function register) is a control register for a peripheral function. Tables 4.1 to 4.7 list the special function registers.

Address	Register	Symbol	After reset
0000h			
0001h			
0002h			
0003h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CM0	01101000b
0007h	System Clock Control Register 1	CM1	0010000b
0008h			
0009h			
000Ah	Protect Register	PRCR	00h
000Bh			
000Ch	Oscillation Stop Detection Register	OCD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000Fh	Watchdog Timer Control Register	WDC	00X11111b
0010h	Address Match Interrupt Register 0	RMAD0	00h
0011h			00h
0012h			00h
0013h	Address Match Interrupt Enable Register	AIER	00h
0014h	Address Match Interrupt Register 1	RMAD1	00h
0015h			00h
0016h			00h
0017h			
0018h			
0019h			
001Ah			
001Bh			
001Ch	Count Source Protection Mode Register	CSPR	00h 10000000b <sup>(6)</sup>
001Dh			
001Eh			
001Fh			
0020h			
0021h			
0022h			
0023h	High-Speed On-Chip Oscillator Control Register 0	FRA0	00h
0024h	High-Speed On-Chip Oscillator Control Register 1	FRA1	When shipping
0025h	High-Speed On-Chip Oscillator Control Register 2	FRA2	00h
0026h			
0027h			
0028h			
0029h			
002Ah			
002Bh	High-Speed On-Chip Oscillator Control Register 6	FRA6	When Shipping
002Ch	High-Speed On-Chip Oscillator Control Register 7	FRA7	When Shipping
0030h	1		
0031h	Valtage Detection Desigter (2)		00001000b

#### SFR Information (1)<sup>(1)</sup> Table 4.1

0030h			
0031h	Voltage Detection Register 1 <sup>(2)</sup>	VCA1	00001000b
0032h	Voltage Detection Register 2 <sup>(2)</sup>	VCA2	00h <sup>(3)</sup>
			0010000b <sup>(4)</sup>
0033h			
0034h			
0035h			
0036h	Voltage Monitor 1 Circuit Control Register <sup>(5)</sup>	VW1C	00001000b
0037h	Voltage Monitor 2 Circuit Control Register <sup>(5)</sup>	VW2C	00h
0038h	Voltage Monitor 0 Circuit Control Register <sup>(2)</sup>	VW0C	0000X000b <sup>(3)</sup>
			0100X001b <sup>(4)</sup>
0039h			
003Ah			

003Fh

X: Undefined NOTES:

The blank regions are reserved. Do not access locations in these regions. Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register. The LVD0ON bit in the OFS register is set to 1 and hardware reset. 1. 2.

3.

Power-on reset, voltage monitor 0 reset, or the LVD00N bit in the OFS register is set to 0 and hardware reset. Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect b2 and b3. The CSPROINI bit in the OFS register is set to 0.

4. 5.

6.



Address	Register	Symbol	After reset
00C0h	A/D Register	AD	XXh
00C1h		, (2	XXh
00C2h			AAII
00C3h			
00C4h			
00C5h			
00C6h			
00C7h			
00C8h			
00C9h			
00CAh			
00CBh			
00CCh			
00CDh			
00CEh			
00CFh			
00D0h			
00D1h			
00D2h			1
00D3h			1
00D4h	A/D Control Register 2	ADCON2	00h
00D411			1
00D5h	A/D Control Register 0	ADCON0	00h
	A/D Control Desister 1		
00D7h	A/D Control Register 1	ADCON1	00h
00D8h			
00D9h			
00DAh			
00DBh			
00DCh			
00DDh			
00DEh			
00DFh		-	
00E0h	Dort DO Dorigtor	D0	XXh
	Port PO Register	P0	
00E1h	Port P1 Register	P1	XXh
00E2h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
00E4h	Port P2 Register	P2	XXh
00E5h	Port P3 Register	P3	XXh
00E6h	Port P2 Direction Register	PD2	00h
00E7h	Port P3 Direction Register	PD3	00h
00E8h	Port P4 Register	P4	XXh
00E9h		14	AAII
	Dest D4 Direction Destates		0.01
00EAh	Port P4 Direction Register	PD4	00h
00EBh			1
00ECh			
00EDh			
00EEh			
00EFh			1
00F0h			1
00F1h		1	1
00F2h		+	1
00F2h			1
	   Dent D0 Drive Organity Organization	DODDD	0.01
00F4h	Port P2 Drive Capacity Control Register	P2DRR	00h
00F5h	Pin Select Register 1	PINSR1	XXh
00F6h	Pin Select Register 2	PINSR2	XXh
00F7h	Pin Select Register 3	PINSR3	XXh
00F8h	Port Mode Register	PMR	00h
00F9h	External Input Enable Register	INTEN	00h
00FAh	INT Input Filter Select Register	INTE	00h
00FBh	Key Input Enable Register	KIEN	00h
00FCh		PUR0	00h
	Pull-Up Control Register 0		
00FDh	Pull-Up Control Register 1	PUR1	XX000000b
00FEh			
00FFh			
Villadofinad			

#### SFR Information (4)<sup>(1)</sup> Table 4.4

X: Undefined NOTE: 1. The blank regions are reserved. Do not access locations in these regions.

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Address	Register	Symbol	After reset
0100h		,	
	Timer RA Control Register	TRACR	00h
0101h	Timer RA I/O Control Register	TRAIOC	00h
0102h	Timer RA Mode Register	TRAMR	00h
0103h	Timer RA Prescaler Register	TRAPRE	FFh
0104h	Timer RA Register	TRA	FFh
0105h	LIN Control Register 2	LINCR2	00h
	LIN Control Register		00h
0106h		LINCR	
0107h	LIN Status Register	LINST	00h
0108h	Timer RB Control Register	TRBCR	00h
0109h	Timer RB One-Shot Control Register	TRBOCR	00h
010Ah	Timer RB I/O Control Register	TRBIOC	00h
010Bh	Timer RB Mode Register	TRBMR	00h
010Ch	Timer RB Prescaler Register	TRBPRE	FFh
010Dh	Timer RB Secondary Register	TRBSC	FFh
010Eh	Timer RB Primary Register	TRBPR	FFh
010Fh			
0110h			
0111h			
0112h			
0112h			łł
			ļ
0114h			
0115h			
0116h			
0117h			
0118h		1	
0119h			
011Ah			
011Bh			
011Ch			
011Dh			
011Eh			
011Fh			
0120h	Timer RC Mode Register	TRCMR	01001000b
0120h	Timer RC Control Register 1	TRCCR1	000h
0122h	Timer RC Interrupt Enable Register	TRCIER	01110000b
0123h	Timer RC Status Register	TRCSR	01110000b
0124h	Timer RC I/O Control Register 0	TRCIOR0	10001000b
0125h	Timer RC I/O Control Register 1	TRCIOR1	10001000b
0126h	Timer RC Counter	TRC	00h
0127h			00h
0128h	Timer RC General Register A	TRCGRA	FFh
		TRUGRA	
0129h		TROOPR	FFh
012Ah	Timer RC General Register B	TRCGRB	FFh
012Bh			FFh
012Ch	Timer RC General Register C	TRCGRC	FFh
012Dh			FFh
012Eh	Timer RC General Register D	TRCGRD	FFh
012Eh			FFh
	Timer DC Centrel Degister 2	TROOPS	
0130h	Timer RC Control Register 2	TRCCR2	00011111b
0131h	Timer RC Digital Filter Function Select Register	TRCDF	00h
0132h	Timer RC Output Master Enable Register	TRCOER	01111111b
0133h			
0134h			
0135h			
0136h			
	Timer DD Stort Deviator	TDDOTD	11111100b
0137h	Timer RD Start Register	TRDSTR	11111100b
0138h	Timer RD Mode Register	TRDMR	00001110b
0139h	Timer RD PWM Mode Register	TRDPMR	10001000b
013Ah	Timer RD Function Control Register	TRDFCR	1000000b
013Bh	Timer RD Output Master Enable Register 1	TRDOER1	FFh
013Ch	Timer RD Output Master Enable Register 2	TRDOER2	01111111b
013Dh	Timer RD Output Control Register	TRDOCR	00h
013Eh	Timer RD Digital Filter Function Select Register 0	TRDDF0	00h
013Fh	Timer RD Digital Filter Function Select Register 1	TRDDF1	00h

#### SFR Information (5)<sup>(1)</sup> Table 4.5

NOTE: 1. The blank regions are reserved. Do not access locations in these regions

## 5. Electrical Characteristics

The electrical characteristics of N version (Topr =  $-20^{\circ}$ C to  $85^{\circ}$ C) and D version (Topr =  $-40^{\circ}$ C to  $85^{\circ}$ C) are listed below.

Please contact Renesas Technology sales offices for the electrical characteristics in the Y version (Topr =  $-20^{\circ}$ C to  $105^{\circ}$ C).

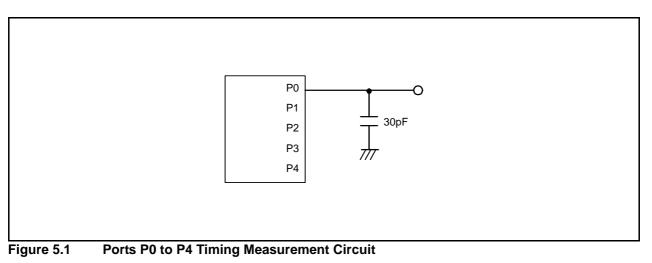
#### Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
Vi	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	Topr = 25°C	500	mW
Topr	Operating ambient temperature		-20 to 85 (N version) / -40 to 85 (D version)	°C
Tstg	Storage temperature		-65 to 150	°C

Cumbal	Parameter	Conditions	Standard			Unit	
Symbol		Conditions		Min.	Тур.	Max.	Unit
-	Resolution		Vref = AVCC	-	-	10	Bits
-	Absolute	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±3	LSB
	accuracy	8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±2	LSB
		10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±5	LSB
		8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	-	40	kΩ
tconv	Conversion time	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	3.3	-	-	μS
		8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	2.8	-	-	μS
Vref	Reference voltage			2.2	-	AVcc	V
Via	Analog input voltage <sup>(2)</sup>			0	-	AVcc	V
-	A/D operating	A/D operating Without sample and hold	$V_{ref} = AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}$	0.25	_	10	MHz
	clock frequency	With sample and hold	Vref = AVcc = 2.7 to 5.5 V	1	-	10	MHz

Table 5.3	A/D Converter	Characteristics

 AVcc = 2.7 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
 When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

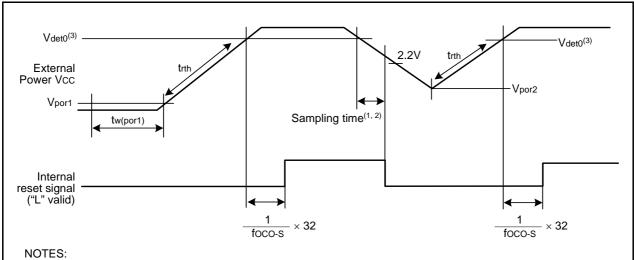


Symbol	Parameter	Condition		Unit			
Symbol Farameter		Condition	Min.	Тур.	Max.	Unit	
Vpor1	Power-on reset valid voltage <sup>(4)</sup>		-	-	0.1	V	
Vpor2	Power-on reset or voltage monitor 0 reset valid voltage		0	-	Vdet0	V	
trth	External power Vcc rise gradient <sup>(2)</sup>		20	-	-	mV/msec	

Table 5.9 Power-on Reset Circuit, Voltage Monitor 0 Reset Electrical Characteristics	;s(3)
--	-------

1. The measurement condition is  $T_{opr} = -20$  to  $85^{\circ}C$  (N version) / -40 to  $85^{\circ}C$  (D version), unless otherwise specified.

- 2. This condition (external power Vcc rise gradient) does not apply if Vcc  $\ge$  1.0 V.
- 3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
- 4.  $t_{w(por1)}$  indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain  $t_{w(por1)}$  for 30 s or more if  $-20^{\circ}C \le T_{opr} \le 85^{\circ}C$ , maintain  $t_{w(por1)}$  for 3,000 s or more if  $-40^{\circ}C \le T_{opr} < -20^{\circ}C$ .



- 1. When using the voltage monitor 0 digital filter, ensure that the voltage is within the MCU operation voltage range (2.2 V or above) during the sampling time.
- 2. The sampling clock can be selected. Refer to 6. Voltage Detection Circuit for details.
- 3. Vdet0 indicates the voltage detection level of the voltage detection 0 circuit. Refer to **6. Voltage Detection Circuit** for details.

Figure 5.3 Reset Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	Offic
fOCO40M	High-speed on-chip oscillator frequency	Vcc = 2.7 V to 5.5 V	39.2	40	40.8	MHz
	temperature • supply voltage dependence	$-20^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(2)}$				
		Vcc = 2.7 V to 5.5 V	39.0	40	41.0	MHz
		$-40^\circ C \leq T_{opr} \leq 85^\circ C^{(2)}$				
		Vcc = 2.2 V to 5.5 V	35.2	40	44.8	MHz
		$-20^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(3)}$				
		Vcc = 2.2 V to 5.5 V	34.0	40	46.0	MHz
		$-40^\circ C \leq T_{opr} \leq 85^\circ C^{(3)}$				
	High-speed on-chip oscillator frequency when	Vcc = 5.0 V, Topr = 25°C	-	36.864	-	MHz
	correction value in FRA7 register is written to	Vcc = 2.7 V to 5.5 V	-3%	-	3%	%
	FRA1 register <sup>(4)</sup>	$-20^{\circ}C \le T_{opr} \le 85^{\circ}C$				
-	Value in FRA1 register after reset		08h	-	F7h	-
_	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	_	MHz
-	Oscillation stability time	Vcc = 5.0 V, Topr = 25°C	-	10	100	μs
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	550	-	μΑ

**Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics** 

1. Vcc = 2.2 to 5.5 V,  $T_{opr} = -20$  to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified. 2. These standard values show when the FRA1 register value after reset is assumed.

3. These standard values show when the corrected value of the FRA6 register is written to the FRA1 register.

4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

#### Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falanielei	Condition	Min.	Тур.	Max.	Unit
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
-	Oscillation stability time		-	10	100	μS
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	15	-	μA

NOTE:

1. Vcc = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

#### Table 5.12 **Power Supply Circuit Timing Characteristics**

Symbol	Parameter	Condition		Unit		
Symbol		Condition	Min.	Тур.	Max.	Onit
td(P-R)	Time for internal power supply stabilization during power-on <sup>(2)</sup>		1	-	2000	μS
td(R-S)	STOP exit time <sup>(3)</sup>		-	-	150	μS

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NOTES:

The measurement condition is Vcc = 2.2 to 5.5 V and Topr = 25°C.
 Waiting time until the internal power supply generation circuit stabilizes during power-on.

3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

Symbol	Parameter		Cond	lition	S	tandard		Unit
Symbol	Pala	inelei	Cond	illion	Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Except P2_0 to P2_7, XOUT	Iон = -1 mA		Vcc - 0.5	_	Vcc	V
		P2_0 to P2_7	Drive capacity HIGH	Iон = -5 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Iон = -1 mA	Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Іон = –50 μА	Vcc - 0.5	-	Vcc	V
Vol	Output "L" voltage	Except P2_0 to P2_7, XOUT	IoL = 1 mA	·	-	-	0.5	V
		P2_0 to P2_7	Drive capacity HIGH	IOL = 5 mA	-	-	0.5	V
			Drive capacity LOW	IOL = 1 mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1 mA	-	-	0.5	V
			Drive capacity LOW	IOL = 50 μA	-	-	0.5	V
VT+-VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD2, CLK0, CLK2			0.1	0.3	-	V
		RESET			0.1	0.4	-	V
Ін	Input "H" current		VI = 3 V, Vcc = 3 V		-	_	4.0	μA
lı∟	Input "L" current		VI = 0 V, Vcc = 3	V	-	-	-4.0	μA
Rpullup	Pull-up resistance		VI = 0 V, Vcc = 3	V	66	160	500	kΩ
RfXIN	Feedback resistance	XIN			-	3.0	-	MΩ
Vram	RAM hold voltage		During stop mode	e	1.8	-	-	V

 Table 5.20
 Electrical Characteristics (1) [Vcc = 3 V]

1. Vcc =2.7 to 3.3 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 10 MHz, unless otherwise specified.

# Table 5.21Electrical Characteristics (2) [Vcc = 3 V]<br/>(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter		Condition		Standard	t	Unit
Symbol	Falameter		Condition	Min.	Тур.	Max.	Unit
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	_	mA
	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	2	_	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5	9	mA
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	_	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	130	300	μA
W	Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	25	70	μΑ	
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	55	μΑ
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0		0.7	3.0	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μA

#### Timing requirements (Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

#### Table 5.22 XIN Input

Symbol	Symbol Parameter		Standard		
Symbol			Max.	Unit	
tc(XIN)	XIN input cycle time	100	-	ns	
twh(xin)	XIN input "H" width	40	-	ns	
twl(XIN)	XIN input "L" width	40	-	ns	

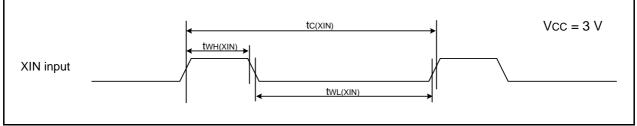


Figure 5.8 XIN Input Timing Diagram when Vcc = 3 V

#### Table 5.23 TRAIO Input

Symbol	Parameter		Standard		
Symbol		Min.	Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	300	=	ns	
twh(traio)	TRAIO input "H" width	120	-	ns	
twl(traio)	TRAIO input "L" width	120	-	ns	

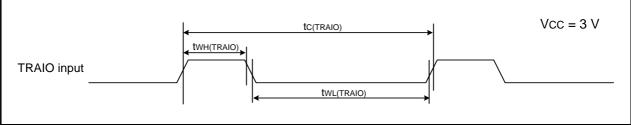


Figure 5.9 TRAIO Input Timing Diagram when Vcc = 3 V

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